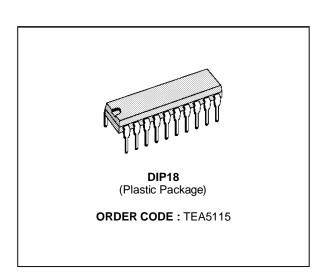


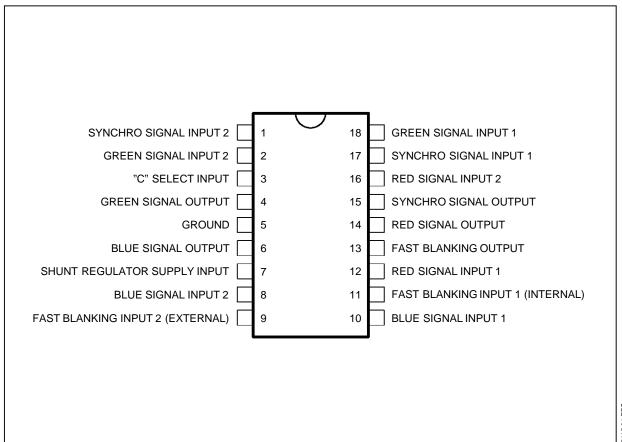
TEA5115

5 CHANNELS VIDEO SWITCH

- EACH CHANNEL EXCEPT FAST BLANKING HAS 6dB GAIN
- R, G, B AND VIDEO SIGNALS ARE CLAMPED TO THE SAME REFERENCE VOLTAGE IN OR-DER TO HAVE NO OUTPUT DIFFERENTIAL VOLTAGE WHEN SWITCHING
- ALL INPUT LEVELS COMPATIBLE WITH NFC 92250 AND EN 50049 NORMS
- 30MHz BAND WIDTH FOR R, G, B SIGNALS
- INTERNAL 6.7V SHUNT REGULATOR FOR:
 - LOW IMPEDANCE LOADS,
 - POWER DISSIPATION LIMITATION
- INDEPENDANT VIDEO OR SYNCHRONIZING SIGNAL SELECTION
- SIMULTANEOUS SWITCHING OF R, G, B AND FB SIGNALS BY FB1 INPUT (internal)



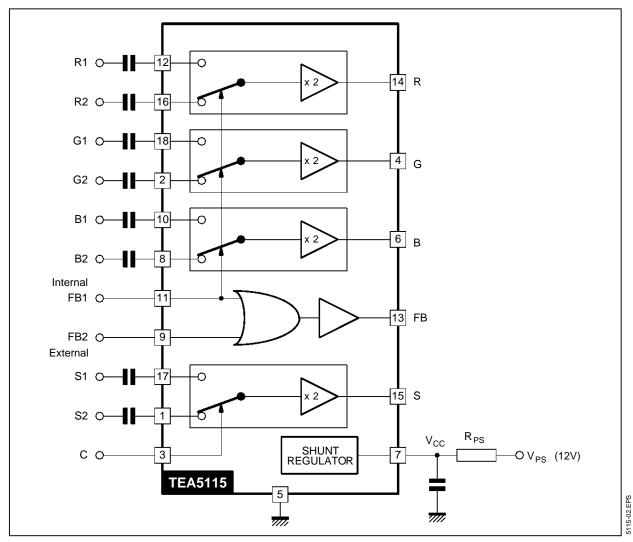
PIN CONNECTIONS



September 1993 1/10

5115-01.EPS

BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
Icc	Supply Current (see note)	150	mA
V _{in}	Input Voltage (all inputs)	- 0.5 to V _{CC} + 0.5	V
T _{oper}	Operating Temperature Range	0 to 70	°C
Tj	Junction Temperature	- 40 to + 150	°C
T _{stg}	Storage Temperature	- 40 to + 150	°C

Note: Minimum output load is 300 Ω in case of all outputs loaded.

THERMAL DATA

Symbol	Parameter	Value	Unit
R _{th (j-a)}	Junction-ambient Thermal Resistance	70	°C/W

SGS-THOMSON MICROELECTRONICS

ELECTRICAL CHARACTERISTICS

 T_{amb} = + 25 °C, I_{CC} = 120 mA ; Load value = 150 Ω (sequentially switched) (unless otherwise specified, refer to test circuit page 7)

Symbol	Parame	Min.	Тур.	Max.	Unit	
Vcc	Internal Shunt Regulator	I_{CC} = 120 mA I_{CC} = 90 mA I_{CC} = 150 mA	6.3 6.2 6.2	6.7	7.2 7.3 7.3	V V V

R, G, B Switches (pins 4, 6, 14) (Time Measurement Conditions : Δ inputs RGB = 0.7 V_{pp} ; FB input pulse amplitude = 2 V)

Vc	DC Output Voltage T _{junction} = 25 °C		0.9	1.25	V
	(no input voltage) T _{junction} stabilized		1.2	0	_
V _{AC}	Max Output Swing Voltage	2	4.0		V_{pp}
В	Bandwidth (- 3 dB) (input voltage 0.7 V _{pp})	20	30		MHz
A _v	Gain of Each Channel (input voltage 0.7 V _{pp} ; f = 1MHz)	5.5	6	6.5	dB
A _{dc}	Gain Difference Between any two R, G, B Channels (input voltage 0.7 V_{pp} ; f = 1 MHz)		0.1	0.5	dB
	Input Swing		0.7 V ± 3dB		
Z _{ic}	DC Input Impedance		10		kΩ
Z _{oc}	Dynamic Output Impedance (input voltage 0.7 V_{pp} ; f = 1MHz) with R _{load} = 300 Ω		10		Ω
	Crosstalk between any inputs (R1 and R2 or B1 and B2 or G1 and G2) (input voltage 0.7 V_{pp} ; f = 1 MHz).	45	55		dB
	Crosstalk between any outputs (input voltage 0.7 V_{pp} ; f = 1 MHz).	40	55		dB
t _{dc}	Delay time between R, G, B inputs and RGB outputs.		10		ns
t _{sr1}	Switching rise time between FB1 input signal and R, G, B output signal.		60	110	ns
t _{sf1}	Switching fall time between FB1 input signal and R, G, B output signal.		10	40	ns
t _{sr2}	Switching rise time between FB2 input signal and R, G, B output signal.		10		ns
t _{sf2}	Switching fall time between FB2 input signal and R, G, B output signal.		10		ns
t _{d11} t _{d12}	R1, G1, B1 Decay Time		30 60		ns ns
t _{d21} t _{d22}	R2, G2, B2 Decay Time		45 40		ns ns

Fast Blanking Switch (pin 13)

(time measurement conditions : FB input pulse amplitude = 2 V)

(time mea	surement conditions : FB input puise amplit	ude = 2 V)				
VIL VIH VIH VOL VOH	Low Level Input Voltage FB1 and FB2 High Level Input Voltage FB2 External High Level Input Voltage FB1 Internal Low Level Output Voltage High Level Output Voltage	T _{junction} = 25°C T _{junction} stabilized	- 0.5 1 1.2 1.4 1.5	1.7 1.9	0.45 V _{CC} +0.5 V _{CC} +0.5 0.6 3.5	V V V V
	Input Current (without load)			1.5		μΑ
	Dynamic Output Impedance: with Rload :	= 300 Ω		10		Ω
t _{FB1r}	Switching rise time between FB1 input a	nd FB output.		120	160	ns
t _{FB1f}	Switching fall time between FB1 input an	d FB output.		25	60	ns
t _{FB2r}	Switching rise time between FB2 input a	nd FB output.		70		ns
t _{FB2f}	Switching fall time between FB2 input an	d FB output.		35		ns
d _{tr}	Delay Between RGB Output Signal and (rise time)		50	100	ns	
d _{tf}	Delay Between RGB Output Signal and (fall time)	FB Output Signal		20	40	ns

ELECTRICAL CHARACTERISTICS (continued)

 T_{amb} = + 25 °C, $~I_{CC}$ = 120 mA ; Load value = 150 Ω

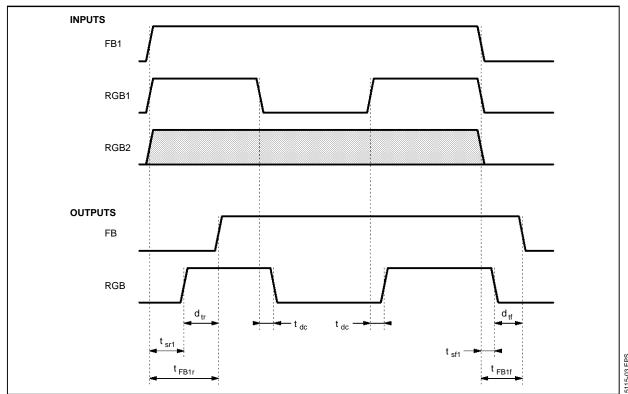
(sequentially switched) (unless otherwise specified, refer to test circuit page 7)

Symbol	Parameter	Min.	Тур.	Max.	Unit
Video (or syn	nchro) Signal Switch (pin 15)				•
Vs	DC Output Voltage (no input voltage) $T_{junction} = 25^{\circ}C$ $T_{junction} \text{ stabilized}$		0.9 1.2	1.25	V
	Max Output Swing Voltage DC Input Impedance	2.6	10		V _{pp} kΩ
	Dynamic Output Impedance (input voltage $1V_{pp}$; f = $1MHz$) with $R_{load} = 300 \Omega$		10		Ω
	Gain (input voltage 1 V _{pp} ; f = 1MHz) Bandwidth (– 3 dB) (input voltage 1 V _{pp})	5.5 15	6 20	6.5	dB MHz
	Input Swing		1V ± 3 dB		
t _{cr}	Switching rise time between C input signal and S output signal (C pulse amplitude 3 V).		30		ns
t _{cf}	Switching fall time between C input signal and S output signal (C pulse amplitude 3 V).		10		ns
t _{dc}	Delay Time Between S Input and S Output (Δ input 0.7 V _{pp})		10		ns

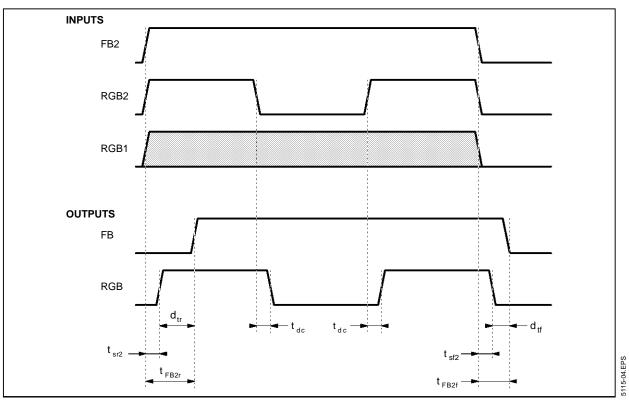
Select Input "C" (pin 3)

VIL VIH IIL IIH	Low Level Input Voltage High Level Input Voltage Low Level Input Current (V _{IL} = 1 V) High Level Input Current (V _{IH} = 3 V)	- 0.5 2 - 0.6	1 V _{CC} +0.5 - 0.1 0.5	V V mA mA	115-04.TBL
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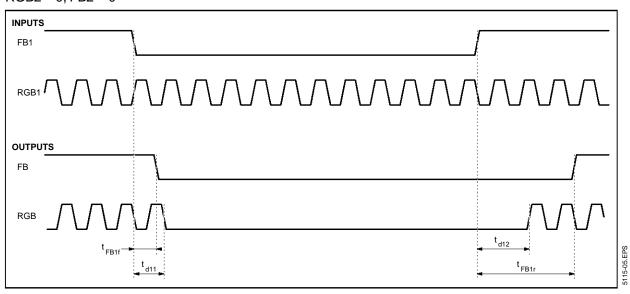
FB2 = 0



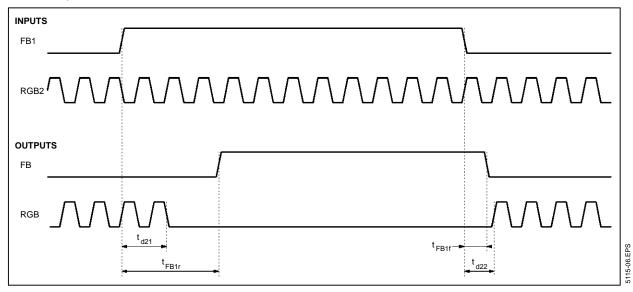
FB1 = 0

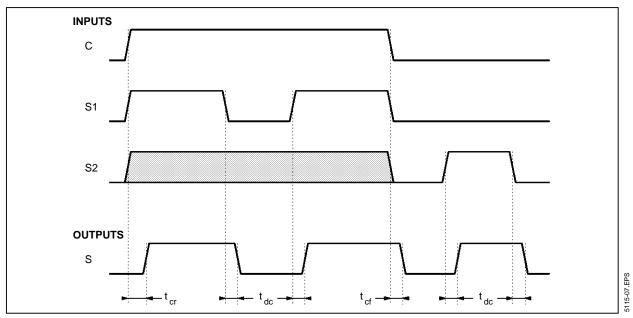


RGB2 = 0, FB2 = 0

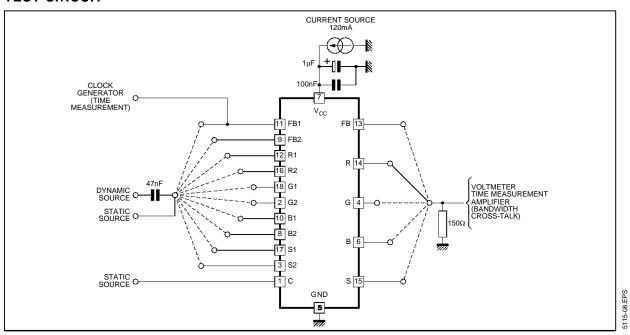


RGB1 = 0, FB2 = 0



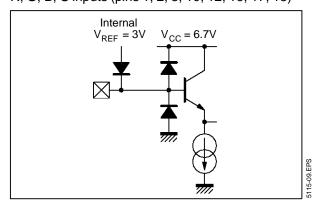


TEST CIRCUIT

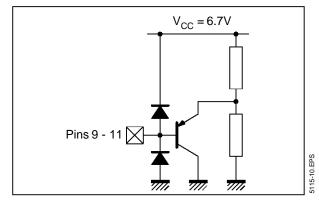


INPUTS/OUTPUTS EQUIVALENT INTERNAL DIAGRAMS

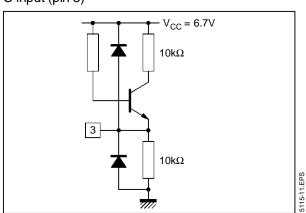
R, G, B, S inputs (pins 1, 2, 8, 10, 12, 16, 17, 18)



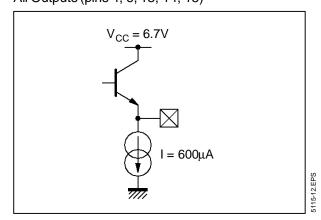
FB inputs (pins 9, 11)



C input (pin 3)

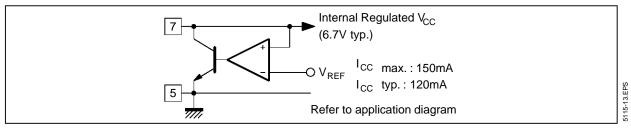


All Outputs (pins 4, 6, 13, 14, 15)

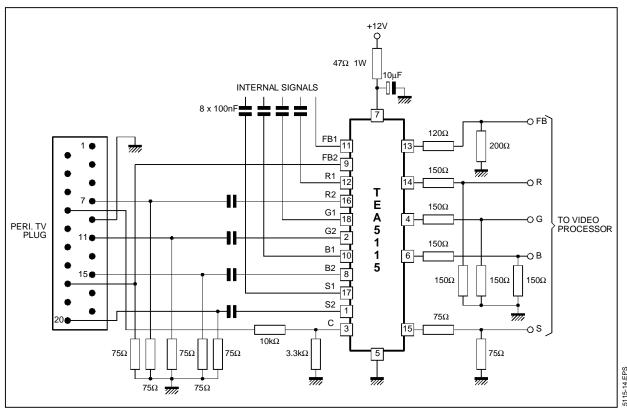


INPUTS/OUTPUTS EQUIVALENT INTERNAL DIAGRAMS (continued)

I_{CC} Supply (shunt transistor regulation system) (Pin 7)

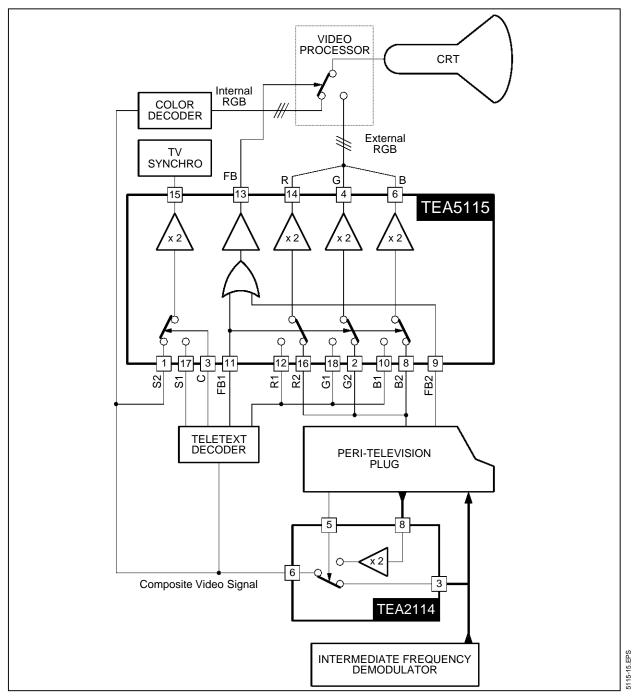


TYPICAL APPLICATION DIAGRAM



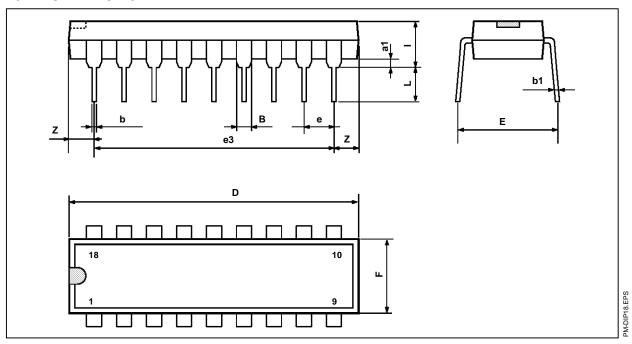
- Above given output load values are minimum values, in case of all output loading.
- Minimum output load is 150 Ω individually, provided that total supply current is less than 150 mA.

TELETEXT SWITCHING APPLICATION WITH TEA5115 AND TEA2114



PACKAGE MECHANICAL DATA

18 PINS - PLASTIC DIP



Dimensions		Millimeters			Inches	
	Min.	Тур.	Max.	Min.	Тур.	Max.
a1	0.254			0.010		
В	1.39		1.65	0.055		0.064
b		0.46			0.018	
b1		0.25			0.010	
D			23.24			0.914
E		8.5			0.335	
е		2.54			0.100	
e3		20.32			0.800	
F			7.1			0.280
i			3.93			0.155
L		3.3			0.130	
Z		1.27	1.59		0.050	0.062

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